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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Details	
Product Status	Active
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I ² C, LINbus, SIO, SSU, UART/USART
Peripherals	POR, Voltage Detect, WDT
Number of I/O	41
Program Memory Size	16KB (16K × 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 5.5V
Data Converters	A/D 12x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	52-LQFP
Supplier Device Package	52-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f21254sdfp-v2

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

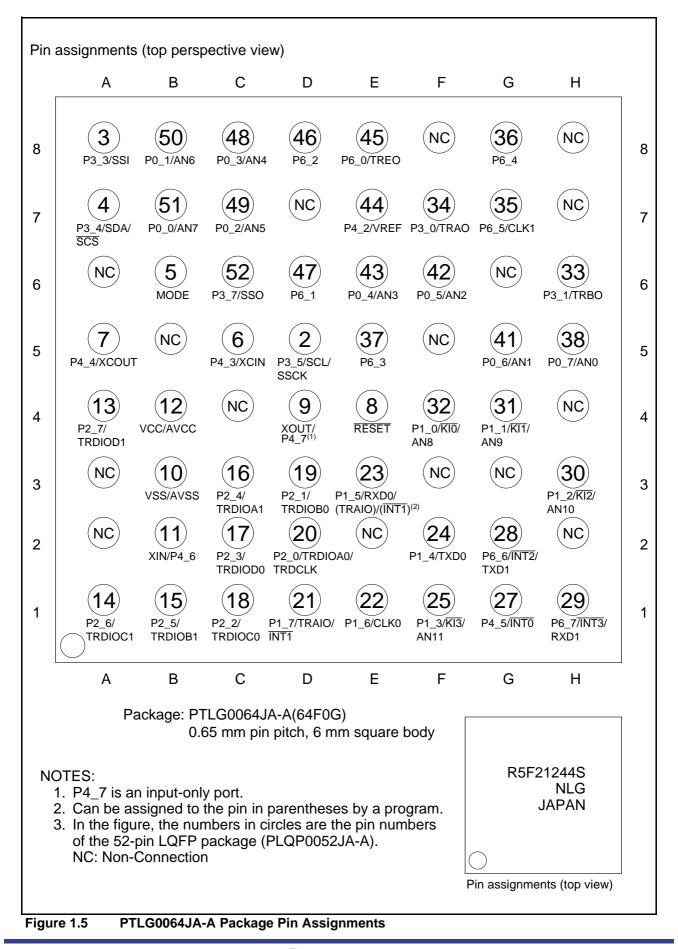
Type No.	ROM C	apacity	RAM	Package Type	Remarks
Type No.	Program ROM	Data flash	Capacity	Fackage Type	Remarks
R5F21254SNFP	16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0052JA-A	N version
R5F21255SNFP	24 Kbytes	1 Kbyte x 2	2 Kbytes	PLQP0052JA-A	Blank product
R5F21256SNFP	32 Kbytes	1 Kbyte x 2	2 Kbytes	PLQP0052JA-A	
R5F21257SNFP	48 Kbytes	1 Kbyte x 2	2.5 Kbytes	PLQP0052JA-A	
R5F21258SNFP	64 Kbytes	1 Kbyte x 2	3 Kbytes	PLQP0052JA-A	
R5F21254SNLG	16 Kbytes	1 Kbyte x 2	1 Kbyte	PTLG0064JA-A	
R5F21256SNLG	32 Kbytes	1 Kbyte x 2	2 Kbytes	PTLG0064JA-A	
R5F21254SDFP	16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0052JA-A	D version
R5F21255SDFP	24 Kbytes	1 Kbyte x 2	2 Kbytes	PLQP0052JA-A	Blank product
R5F21256SDFP	32 Kbytes	1 Kbyte x 2	2 Kbytes	PLQP0052JA-A	
R5F21257SDFP	48 Kbytes	1 Kbyte x 2	2.5 Kbytes	PLQP0052JA-A	
R5F21258SDFP	64 Kbytes	1 Kbyte x 2	3 Kbytes	PLQP0052JA-A	
R5F21254SNXXXFP	16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0052JA-A	N version
R5F21255SNXXXFP	24 Kbytes	1 Kbyte x 2	2 Kbytes	PLQP0052JA-A	Factory
R5F21256SNXXXFP	32 Kbytes	1 Kbyte x 2	2 Kbytes	PLQP0052JA-A	programming
R5F21257SNXXXFP	48 Kbytes	1 Kbyte x 2	2.5 Kbytes	PLQP0052JA-A	product ⁽¹⁾
R5F21258SNXXXFP	64 Kbytes	1 Kbyte x 2	3 Kbytes	PLQP0052JA-A	
R5F21254SNXXXLG	16 Kbytes	1 Kbyte x 2	1 Kbyte	PTLG0064JA-A	
R5F21256SNXXXLG	32 Kbytes	1 Kbyte x 2	2 Kbytes	PTLG0064JA-A	
R5F21254SDXXXFP	16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0052JA-A	D version
R5F21255SDXXXFP	24 Kbytes	1 Kbyte x 2	2 Kbytes	PLQP0052JA-A	Factory
R5F21256SDXXXFP	32 Kbytes	1 Kbyte x 2	2 Kbytes	PLQP0052JA-A	programming
R5F21257SDXXXFP	48 Kbytes	1 Kbyte x 2	2.5 Kbytes	PLQP0052JA-A	product ⁽¹⁾
R5F21258SDXXXFP	64 Kbytes	1 Kbyte x 2	3 Kbytes	PLQP0052JA-A	1

Table 1.4 Product Information for R8C/25 Group

Current of Feb. 2008

NOTE:

1. The user ROM is programmed before shipment.



1.6 Pin Functions

Table 1.5 lists Pin Functions.

Table 1.5Pin Functions

Туре	Symbol	I/O Type	Description
Power supply input	VCC, VSS	I	Apply 2.2 V to 5.5 V to the VCC pin. Apply 0 V to the VSS pin.
Analog power	AVCC, AVSS	I	Power supply for the A/D converter.
supply input			Connect a capacitor between AVCC and AVSS.
Reset input	RESET	I	Input "L" on this pin resets the MCU.
MODE	MODE	I	Connect this pin to VCC via a resistor.
XIN clock input	XIN	I	These pins are provided for XIN clock generation circuit I/O. Connect a ceramic resonator or a crystal oscillator between
XIN clock output	XOUT	0	the XIN and XOUT pins. To use an external clock, input it to the XIN pin and leave the XOUT pin open.
XCIN clock input	XCIN	I	These pins are provided for XCIN clock generation circuit I/O. Connect a crystal oscillator between the XCIN and XCOUT
XCIN clock output	XCOUT	0	pins. To use an external clock, input it to the XCIN pin and leave the XCOUT pin open.
INT interrupt input	INT0 to INT3	I	INT interrupt input pins. INT0 is timer RD input pin. INT1 is timer RA input pin.
Key input interrupt	KI0 to KI3	I	Key input interrupt input pins
Timer RA	TRAIO	I/O	Timer RA I/O pin
	TRAO	0	Timer RA output pin
Timer RB	TRBO	0	Timer RB output pin
Timer RD	TRDIOA0, TRDIOA1, TRDIOB0, TRDIOB1, TRDIOC0, TRDIOC1, TRDIOD0, TRDIOD1	I/O	Timer RD I/O ports
	TRDCLK	I	External clock input pin
Timer RE	TREO	0	Divided clock output pin
Serial interface	CLK0, CLK1	I/O	Transfer clock I/O pin
	RXD0, RXD1	I	Serial data input pins
	TXD0, TXD1	0	Serial data output pins
I ² C bus interface	SCL	I/O	Clock I/O pin
	SDA	I/O	Data I/O pin
Clock synchronous	SSI	I/O	Data I/O pin
serial I/O with chip	SCS	I/O	Chip-select signal I/O pin
select	SSCK	I/O	Clock I/O pin
	SSO	I/O	Data I/O pin
Reference voltage input	VREF	I	Reference voltage input pin to A/D converter
A/D converter	AN0 to AN11	I	Analog input pins to A/D converter
I/O port	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0, P3_1, P3_3 to P3_5, P3_7, P4_3 to P4_5, P6_0 to P6_7	I/O	CMOS I/O ports. Each port has an I/O select direction register, allowing each pin in the port to be directed for input or output individually. Any port set to input can be set to use a pull-up resistor or not by a program. P2_0 to P2_7 also function as LED drive ports.
Input port	P4_2, P4_6, P4_7	I	Input-only ports
: Input O: Outp			

I: Input O: Output I/O: Input and output



2.1 Data Registers (R0, R1, R2, and R3)

R0 is a 16-bit register for transfer, arithmetic, and logic operations. The same applies to R1 to R3. R0 can be split into high-order bits (R0H) and low-order bits (R0L) to be used separately as 8-bit data registers. R1H and R1L are analogous to R0H and R0L. R2 can be combined with R0 and used as a 32-bit data register (R2R0). R3R1 is analogous to R2R0.

2.2 Address Registers (A0 and A1)

A0 is a 16-bit register for address register indirect addressing and address register relative addressing. It is also used for transfer, arithmetic, and logic operations. A1 is analogous to A0. A1 can be combined with A0 and as a 32-bit address register (A1A0).

2.3 Frame Base Register (FB)

FB is a 16-bit register for FB relative addressing.

2.4 Interrupt Table Register (INTB)

INTB is a 20-bit register that indicates the start address of an interrupt vector table.

2.5 Program Counter (PC)

PC is 20 bits wide and indicates the address of the next instruction to be executed.

2.6 User Stack Pointer (USP) and Interrupt Stack Pointer (ISP)

The stack pointers (SP), USP, and ISP, are each 16 bits wide. The U flag of FLG is used to switch between USP and ISP.

2.7 Static Base Register (SB)

SB is a 16-bit register for SB relative addressing.

2.8 Flag Register (FLG)

FLG is an 11-bit register indicating the CPU state.

2.8.1 Carry Flag (C)

The C flag retains carry, borrow, or shift-out bits that have been generated by the arithmetic and logic unit.

2.8.2 Debug Flag (D)

The D flag is for debugging only. Set it to 0.

2.8.3 Zero Flag (Z)

The Z flag is set to 1 when an arithmetic operation results in 0; otherwise to 0.

2.8.4 Sign Flag (S)

The S flag is set to 1 when an arithmetic operation results in a negative value; otherwise to 0.

2.8.5 Register Bank Select Flag (B)

Register bank 0 is selected when the B flag is 0. Register bank 1 is selected when this flag is set to 1.

2.8.6 Overflow Flag (O)

The O flag is set to 1 when an operation results in an overflow; otherwise to 0.



3.2 R8C/25 Group

Figure 3.2 is a Memory Map of R8C/25 Group. The R8C/25 group has 1 Mbyte of address space from addresses 00000h to FFFFFh.

The internal ROM (program ROM) is allocated lower addresses, beginning with address 0FFFFh. For example, a 48-Kbyte internal ROM area is allocated addresses 04000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.

The internal ROM (data flash) is allocated addresses 02400h to 02BFFh.

The internal RAM area is allocated higher addresses, beginning with address 00400h. For example, a 2-Kbyte internal RAM is allocated addresses 00400h to 00BFFh. The internal RAM is used not only for storing data but also for calling subroutines and as stacks when interrupt requests are acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated here. All addresses within the SFR, which have nothing allocated are reserved for future use and cannot be accessed by users.

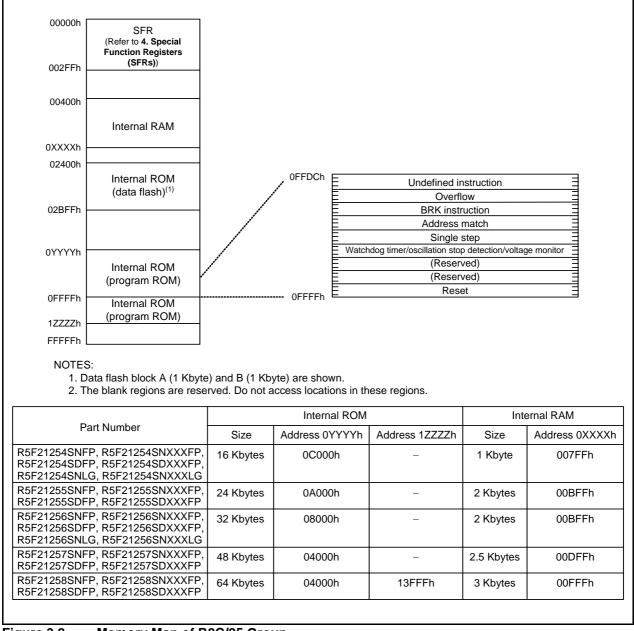


Figure 3.2 Memory Map of R8C/25 Group

Address	Pogister	Symbol	After reset
0080h	Register	Symbol	Alter Teset
0080h			
0081h			
0082h			
0083h			
0084h			
0085h			
0080h			
0087h			
0088h			
0089h			
008Bh 008Ch			
008Dh			
008Eh			
008Fh			
0090h			
0091h			
0092h			
0093h			
0094h			
0095h			
0096h			
0097h			
0098h			
0099h			
009Ah			
009Bh			
009Ch			
009Dh			
009Eh			
009Fh			
00A0h	UART0 Transmit/Receive Mode Register	U0MR	00h
00A1h	UART0 Bit Rate Register	U0BRG	XXh
00A2h	UART0 Transmit Buffer Register	U0TB	XXh
00A3h			XXh
00A4h	UART0 Transmit/Receive Control Register 0	U0C0	00001000b
00A5h	UART0 Transmit/Receive Control Register 1	U0C1	00000010b
00A6h	UART0 Receive Buffer Register	UORB	XXh
00A7h			XXh
00A8h	UART1 Transmit/Receive Mode Register	U1MR	00h
00A9h	UART1 Bit Rate Register	U1BRG	XXh
00AAh	UART1 Transmit Buffer Register	U1TB	XXh
00ABh			XXh
00ACh	UART1 Transmit/Receive Control Register 0	U1C0	00001000b
00ADh	UART1 Transmit/Receive Control Register 1	U1C1	00000010b
00AEh	UART1 Receive Buffer Register	U1RB	XXh
00AFh			XXh
00B0h			
00B1h			
00B2h			
00B3h			
00B4h			
00B5h			
00B6h			
00B7h			-
00B8h	SS Control Register H / IIC bus Control Register 1 ⁽²⁾	SSCRH / ICCR1	00h
00B9h	SS Control Register L / IIC bus Control Register 2 ⁽²⁾	SSCRL / ICCR2	01111101b
00BAh	SS Mode Register / IIC bus Mode Register ⁽²⁾	SSMR / ICMR	00011000b
00BAh 00BBh	SS Enable Register / IIC bus Interrupt Enable Register ⁽²⁾	SSER / ICIER	00h
00BCh	SS Status Register / IIC bus Status Register ⁽²⁾	SSSR / ICSR	00h / 0000X000b
00BDh	SS Mode Register 2 / Slave Address Register ⁽²⁾	SSMR2 / SAR	00h
		SSTDR / ICDRT	FFh
00BEh 00BFh	SS Transmit Data Register / IIC bus Transmit Data Register ⁽²⁾ SS Receive Data Register / IIC bus Receive Data Register ⁽²⁾	SSRDR / ICDRR	FFh

SFR Information (3)⁽¹⁾ Table 4.3

X: Undefined
NOTES:

The blank regions are reserved. Do not access locations in these regions.
Selected by the IICSEL bit in the PMR register.



Address	Register	Symbol	After reset
00C0h	A/D Register	AD	XXh
00C0h	A/D Register	AD	
			XXh
00C2h			
00C3h			
00C4h			
00C5h			
00C6h			
00C7h			
00C8h			
00C9h			
00CAh			
00CAn 00CBh			
00CCh			
00CDh			
00CEh			
00CFh			
00D0h			
00D1h			
00D2h		1	+
00D3h		1	+
00D3h	A/D Control Register 2	ADCON2	00h
00D411 00D5h			
		400010	0.01
00D6h	A/D Control Register 0	ADCON0	00h
00D7h	A/D Control Register 1	ADCON1	00h
00D8h			
00D9h			
00DAh			
00DBh			
00DCh			
00DDh			
00DEh			
00DFh			
00E0h	Port P0 Register	P0	XXh
00E1h	Port P1 Register	P1	XXh
00E2h	Port P0 Direction Register	PD0	00h
00E3h	Port P1 Direction Register	PD1	00h
00E4h	Port P2 Register	P2	XXh
00E5h	Port P3 Register	P3	XXh
00E6h	Port P2 Direction Register	PD2	00h
00E7h	Port P3 Direction Register	PD3	00h
	Port P4 Danister	P4	
00E8h	Port P4 Register	P4	XXh
00E9h			
00EAh	Port P4 Direction Register	PD4	00h
00EBh			
00ECh	Port P6 Register	P6	XXh
00EDh			
00EEh	Port P6 Direction Register	PD6	00h
00EFh			+
00F0h		1	+
00F1h		1	+
00F1h			+
00 501		+	+
00F3h		DODDD	
00F4h	Port P2 Drive Capacity Control Register	P2DRR	00h
00F5h	UART1 Function Select Register	U1SR	XXh
00F6h			
00F7h			
00F8h	Port Mode Register	PMR	00h
00F9h	External Input Enable Register	INTEN	00h
00FAh	INT Input Filter Select Register	INTE	00h
		KIEN	00h
00FBh	Key Input Enable Register		
00FCh	Pull-Up Control Register 0	PUR0	00h
00FDh	Pull-Up Control Register 1	PUR1	XX00XX00b
00FEh			
00FFh			

SFR Information (4)⁽¹⁾ Table 4.4

X: Undefined NOTE: 1. The blank regions are reserved. Do not access locations in these regions.

Address	Register	Symbol	After reset
0140h	Timer RD Control Register 0	TRDCR0	00h
0141h	Timer RD I/O Control Register A0	TRDIORA0	10001000b
0142h	Timer RD I/O Control Register C0	TRDIORC0	10001000b
0143h	Timer RD Status Register 0	TRDSR0	11100000b
0144h	Timer RD Interrupt Enable Register 0	TRDIER0	11100000b
0145h	Timer RD PWM Mode Output Level Control Register 0	TRDPOCR0	11111000b
0146h	Timer RD Counter 0	TRD0	00h
0147h			00h
0148h	Timer RD General Register A0	TRDGRA0	FFh
0149h			FFh
014Ah	Timer RD General Register B0	TRDGRB0	FFh
014Bh			FFh
014Ch	Timer RD General Register C0	TRDGRC0	FFh
014Dh			FFh
014Eh	Timer RD General Register D0	TRDGRD0	FFh
014Fh			FFh
0150h	Timer RD Control Register 1	TRDCR1	00h
0151h	Timer RD I/O Control Register A1	TRDIORA1	10001000b
0152h	Timer RD I/O Control Register C1	TRDIORC1	10001000b
0153h	Timer RD Status Register 1	TRDSR1	1100000b
0154h	Timer RD Interrupt Enable Register 1	TRDIER1	11100000b
0155h	Timer RD PWM Mode Output Level Control Register 1	TRDPOCR1	11111000b
0156h	Timer RD Counter 1	TRD1	00h
0157h	Time DD Connect Desister M	TDDODA	00h FFh
0158h	Timer RD General Register A1	TRDGRA1	
0159h 015Ah	Timer DD Ceneral Degister D4	TRDGRB1	FFh FFh
015An 015Bh	Timer RD General Register B1	IRDGRBI	FFh
015Ch	Timer RD General Register C1	TRDGRC1	FFh
015Dh		INDGRUI	FFh
015Eh	Timer RD General Register D1	TRDGRD1	FFh
015Fh		INDONDI	FFh
0160h			
0161h			
0162h			
0163h			
0164h			
0165h			
0166h			
0167h			
0168h			
0169h			
016Ah			
016Bh			
016Ch			
016Dh			
016Eh			
016Fh			
0170h			
0171h			
0172h			
0173h			<u> </u>
0174h			
0175h			
0176h			
0177h		+	
0178h 0179h			ll
0179h 017Ah			ll
017An 017Bh			
017Bh 017Ch			
017Ch			
017Dh 017Eh		+	
017En		+	
01/111			

SFR Information (6)⁽¹⁾ Table 4.6

X: Undefined NOTE: 1. The blank regions are reserved. Do not access locations in these regions.



Cumb ol		Parameter	Conditions		Standard	1	Unit
Symbol		Parameter	Conditions	Min.	Тур.	Max.	Unit
-	Resolution		Vref = AVCC	-	-	10	Bit
 Absolute 	Absolute	10-bit mode	ϕ AD = 10 MHz, Vref = AVCC = 5.0 V	-	-	±3	LSB
	accuracy	8-bit mode	ϕ AD = 10 MHz, Vref = AVCC = 5.0 V	-	-	±2	LSB
		10-bit mode	ϕ AD = 10 MHz, Vref = AVCC = 3.3 V	-	-	±5	LSB
		8-bit mode	ϕ AD = 10 MHz, Vref = AVCC = 3.3 V	-	-	±2	LSB
		10-bit mode	ϕ AD = 5 MHz, Vref = AVCC = 2.2 V	-	-	±5	LSB
		8-bit mode	ϕ AD = 5 MHz, Vref = AVCC = 2.2 V	-	-	±2	LSB
Rladder	Resistor ladder		Vref = AVCC	10	-	40	kΩ
tconv	Conversion time	10-bit mode	ϕ AD = 10 MHz, Vref = AVCC = 5.0 V	3.3	-	-	μs
		8-bit mode	ϕ AD = 10 MHz, Vref = AVCC = 5.0 V	2.8	-	-	μs
Vref	Reference voltag	e		2.2	-	AVcc	V
Via	Analog input voltage ⁽²⁾			0	-	AVcc	V
-	A/D operating	Without sample and hold	Vref = AVcc = 2.7 to 5.5 V	0.25	-	10	MHz
	clock frequency	With sample and hold	Vref = AVcc = 2.7 to 5.5 V	1	-	10	MHz
		Without sample and hold	Vref = AVcc = 2.2 to 5.5 V	0.25	-	5	MHz
		With sample and hold	Vref = AVcc = 2.2 to 5.5 V	1	-	5	MHz

Table 5.3 A/D Converter Characteristics

NOTES:

1. AVcc = 2.2 to 5.5 V at T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

2. When the analog input voltage is over the reference voltage, the A/D conversion result will be 3FFh in 10-bit mode and FFh in 8-bit mode.

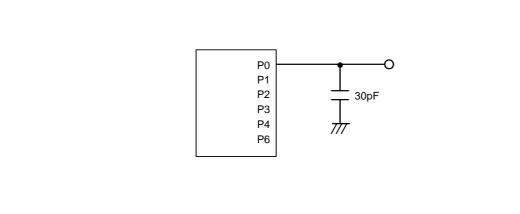


Figure 5.1 Ports P0 to P4, P6 Timing Measurement Circuit

Cumbal	Deremeter	Conditions	Standard			Unit
Symbol	Parameter	Conditions	Min.	Min. Typ. Max.		
-	Program/erase endurance ⁽²⁾	R8C/24 Group	100 ⁽³⁾	-	-	times
		R8C/25 Group	1,000 ⁽³⁾	-	-	times
-	Byte program time		-	50	400	μs
-	Block erase time		-	0.4	9	s
td(SR-SUS)	Time delay from suspend request until suspend		-	-	97+CPU clock × 6 cycles	μS
-	Interval from erase start/restart until following suspend request		650	-	-	μS
-	Interval from program start/restart until following suspend request		0	-	-	ns
-	Time from suspend until program/erase restart		-	-	3+CPU clock × 4 cycles	μS
-	Program, erase voltage		2.7	-	5.5	V
-	Read voltage		2.2	-	5.5	V
-	Program, erase temperature		0	-	60	°C
=	Data hold time ⁽⁷⁾	Ambient temperature = 55°C	20	-	-	year

Table 5.4 Flash Memory (Program ROM) Electrical Characteristics

NOTES: 1. Vcc = 2.7 to 5.5 V at Topr = 0 to 60°C, unless otherwise specified.

2. Definition of programming/erasure endurance The programming and erasure endurance is defined on a per-block basis. If the programming and erasure endurance is n (n = 100 or 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.

However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).

- 4. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erase count of each block and limit the number of erase operations to a certain number.
- 5. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
- 6. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
- 7. The data hold time includes time that the power supply is off or the clock is not supplied.

Symbol	Parameter	Condition		Standard		Unit
			Min.	Тур.	Max.	
Vpor1	Power-on reset valid voltage ⁽⁴⁾		-	-	0.1	V
Vpor2	Power-on reset or voltage monitor 0 reset valid voltage		0	-	Vdet0	V
trth	External power Vcc rise gradient ⁽²⁾		20	-	-	mV/msec

Table 5.9 Power-on Reset Circuit, Voltage Monitor 0 Reset Electrical Characteristics
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NOTES:

- 1. The measurement condition is Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
- 2. This condition (external power Vcc rise gradient) does not apply if $Vcc \ge 1.0$ V.
- 3. To use the power-on reset function, enable voltage monitor 0 reset by setting the LVD0ON bit in the OFS register to 0, the VW0C0 and VW0C6 bits in the VW0C register to 1 respectively, and the VCA25 bit in the VCA2 register to 1.
- 4. $t_{w(por1)}$ indicates the duration the external power Vcc must be held below the effective voltage (Vpor1) to enable a power on reset. When turning on the power for the first time, maintain $t_{w(por1)}$ for 30 s or more if $-20^{\circ}C \le T_{opr} \le 85^{\circ}C$, maintain $t_{w(por1)}$ for 3,000 s or more if $-40^{\circ}C \le T_{opr} < -20^{\circ}C$.

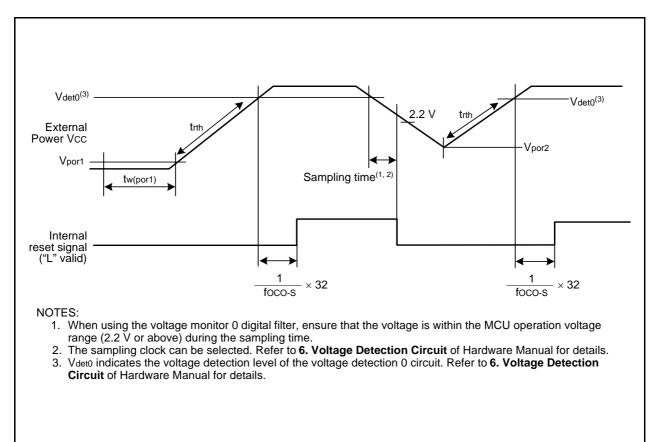


Figure 5.3 Power-on Reset Circuit Electrical Characteristics

Symbol	Parameter	Condition		Standard		Unit
Symbol	Falameter	Condition	Min.	Тур.	Max.	Offic
fOCO40M	High-speed on-chip oscillator frequency temperature • supply voltage dependence	$\label{eq:Vcc} \begin{array}{l} \mbox{Vcc} = 4.75 \mbox{ to } 5.25 \mbox{ V} \\ \mbox{0}^{\circ}\mbox{C} \leq \mbox{Topr} \leq 60^{\circ}\mbox{C}^{(2)} \end{array}$	39.2	40	40.8	MHz
		Vcc = 4.5 to 5.5 V -20°C ≤ Topr ≤ 85°C	38.8	40	40.8	MHz
		Vcc = 4.5 to 5.5 V -40°C ≤ Topr ≤ 85°C	38.4	40	40.8	MHz
		$\label{eq:Vcc} \begin{array}{l} Vcc = 3.0 \ to \ 5.5 \ V \\ -20^{\circ}C \leq T_{opr} \leq 85^{\circ}C^{(2)} \end{array}$	38.8	40	41.2	MHz
		$\label{eq:Vcc} \begin{array}{l} Vcc = 3.0 \ to \ 5.5 \ V \\ -40^{\circ}C \leq T_{opr} \leq 85^{\circ}C^{(2)} \end{array}$	38.4	40	41.6	MHz
		Vcc = 2.7 to 5.5 V -20°C $\leq T_{opr} \leq 85^{\circ}C^{(2)}$	38	40	42	MHz
		Vcc = 2.7 to 5.5 V -40°C $\leq T_{opr} \leq 85^{\circ}C^{(2)}$	37.6	40	42.4	MHz
		Vcc = 2.2 to 5.5 V -20°C $\leq T_{opr} \leq 85^{\circ}C^{(3)}$	35.2	40	44.8	MHz
		$V_{CC} = 2.2 \text{ to } 5.5 \text{ V}$ -40°C $\leq T_{OPT} \leq 85^{\circ}C^{(3)}$	34	40	46	MHz
	High-speed on-chip oscillator frequency when	Vcc = 5.0 V, Topr = 25°C	-	36.864		MHz
	correction value in FRA7 register is written to FRA1 register ⁽⁴⁾	$\label{eq:Vcc} \begin{array}{l} \text{Vcc} = 3.0 \text{ to } 5.5 \text{ V} \\ \text{-}20^\circ\text{C} \leq \text{Topr} \leq 85^\circ\text{C} \end{array}$	-3%	-	3%	%
-	Value in FRA1 register after reset		08h	-	F7h	-
-	Oscillation frequency adjustment unit of high- speed on-chip oscillator	Adjust FRA1 register (value after reset) to -1	-	+0.3	-	MHz
-	Oscillation stability time		-	10	100	μs
-	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	400	-	μA

Table 5.10	High-speed On-Chip Oscillator Circuit Electrical Characteristics
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NOTES:

1. Vcc = 2.2 to 5.5 V, $T_{opr} = -20$ to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

2. Standard values when the FRA1 register value after reset is assumed.

3. Standard values when the corrected value of the FRA6 register has been written to the FRA1 register.

4. This enables the setting errors of bit rates such as 9600 bps and 38400 bps to be 0% when the serial interface is used in UART mode.

Table 5.11 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	neter Condition Standard		Unit		
Symbol	Falameter	Condition	Min.	Тур.	Max.	Unit
fOCO-S	Low-speed on-chip oscillator frequency		30	125	250	kHz
-	Oscillation stability time		-	10	100	μS
-	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	15	-	μA

NOTE:

1. Vcc = 2.2 to 5.5 V, Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

Table 5.12 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Condition				Unit
Symbol	Falanetei	Condition	Min.	Тур.	Max.	Unit
td(P-R)	Time for internal power supply stabilization during power-on ⁽²⁾		1	-	2000	μS
td(R-S)	STOP exit time ⁽³⁾		-	-	150	μS

NOTES:

1. The measurement condition is Vcc = 2.2 to 5.5 V and $T_{opr} = 25^{\circ}C$.

2. Waiting time until the internal power supply generation circuit stabilizes during power-on.

3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.



Table 5.16Electrical Characteristics (2) [Vcc = 5 V]
(Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Deremeter	Parameter Condition	Standard			Unit	
Symbol	Falameter		Min.	Тур.	Max.	Unit	
Icc	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode,	High-speed clock mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	10	17	mA
	output pins are open, other pins are Vss		XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	9	15	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	6	-	mA
			XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	5	-	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	4	-	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	2.5	-	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	10	15	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	4	_	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	5.5	10	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2.5	_	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	_	130	300	μA
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	_	130	300	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	_	30	_	μA

Symbol	Parameter	Sta	Standard	
	Faianetei	Min.	Max.	Unit
tc(CK)	CLKi input cycle time	200	-	ns
tw(CKH)	CLKi input "H" width	100	-	ns
tW(CKL)	CLKi input "L" width	100	-	ns
td(C-Q)	TXDi output delay time	-	50	ns
th(C-Q)	TXDi hold time	-	ns	
tsu(D-C)	RXDi input setup time	50	-	ns
th(C-D)	RXDi input hold time 90 -			

i = 0 or 1

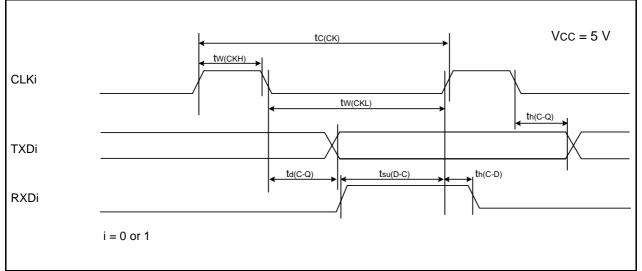




Table 5.21 External Interrupt INTi (i = 0 to 3) Input

Symbol	Parameter	Stan	dard	Unit
Symbol	Falameter	Min.	Max.	Unit
tw(INH)	INTO input "H" width	250 ⁽¹⁾	-	ns
tw(INL)	INTO input "L" width	250(2)	-	ns

NOTES:

1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

2. When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

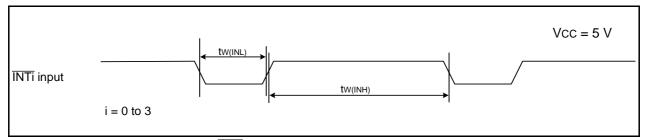


Figure 5.11 External Interrupt INTi Input Timing Diagram when Vcc = 5 V

Table 5.23Electrical Characteristics (4) [Vcc = 3 V]
(Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter		Condition	5	Standar	d	Unit
	Parameter			Min.	Тур.	Max.	Unit
	Power supply current (Vcc = 2.7 to 3.3 V) Single-chip mode, output pins are open,	High-speed clock mode	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	6	-	mA
	other pins are Vss		XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2	_	mA
		High-speed on- chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	5	9	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2	_	mA
		Low-speed on- chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	_	130	300	μA
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	_	130	300	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	_	30	-	μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	25	70	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	23	55	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	3.8	-	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	2.0	_	μA
		Increase during	Without sample & hold	-	0.9	-	mA
		A/D converter operation	With sample & hold	-	0.5	-	mA
		Stop mode	XIN clock off, $T_{opr} = 25^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	0.7	3.0	μA
			VOLUT = VOLUT = VOLUT = 0XIN clock off, $T_{opr} = 85^{\circ}$ CHigh-speed on-chip oscillator offLow-speed on-chip oscillator offCM10 = 1Peripheral clock offVCA27 = VCA26 = VCA25 = 0	_	1.1		μA

Table 5.29Electrical Characteristics (6) [Vcc = 2.2 V]
(Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter		Condition	5	Standar	d	Unit
				Min.	Тур.	Max.	
Icc	Power supply current (Vcc = 2.2 to 2.7 V) Single-chip mode, output pins are open.	High-speed clock mode	XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	3.5	_	mA
	other pins are Vss		XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	1.5	_	mA
		High-speed on- chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 5 MHz Low-speed on-chip oscillator on = 125 kHz No division	-	3.5	-	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 5 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	1.5	_	mA
		Low-speed on- chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	_	100	230	μA
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	_	100	230	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	_	25	_	μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	22	60	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	20	55	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	3.0	_	μΑ
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	1.8	_	μA
		Increase during	Without sample & hold	-	0.4	-	mA
		A/D converter operation	With sample & hold	-	0.3	-	mA
		Stop mode	XIN clock off, $T_{opr} = 25^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	0.7	3.0	μA
			VCA27 = VCA25 = VCA25 = 0XIN clock off, Topr = 85°CHigh-speed on-chip oscillator offLow-speed on-chip oscillator offCM10 = 1Peripheral clock offVCA27 = VCA26 = VCA25 = 0		1.1		μA

Symbol	Parameter	Star	Standard	
	Parameter	Min.	Max.	Unit
tc(CK)	CLKi input cycle time	800	-	ns
tw(ckh)	CLKi input "H" width	400	-	ns
tw(CKL)	CLKi input "L" width	400	-	ns
td(C-Q)	TXDi output delay time	-	200	ns
th(C-Q)	TXDi hold time	-	ns	
tsu(D-C)	RXDi input setup time	150	-	ns
th(C-D)	RXDi input hold time 90 -			

i = 0 or 1

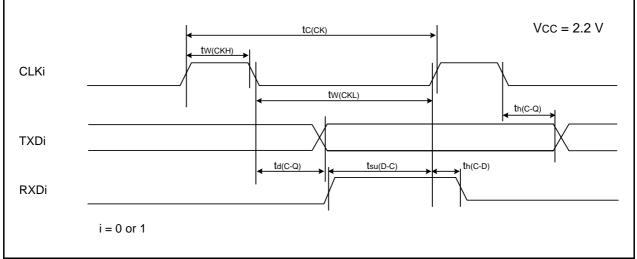




Table 5.33 External Interrupt INTi (i = 0 to 3) Input

Symbol	Parameter	Stan	dard	Unit
Symbol	Falanielei	Min.	Max.	Unit
tw(INH)	INTO input "H" width	1000(1)	-	ns
tw(INL)	INTO input "L" width	1000 ⁽²⁾	-	ns

NOTES:

1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

2. When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

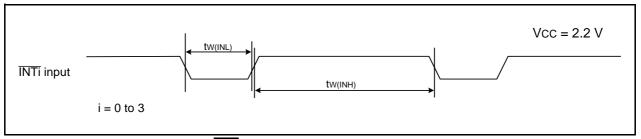


Figure 5.19 External Interrupt INTi Input Timing Diagram when VCC = 2.2 V

REVISION HISTORY

R8C/24 Group, R8C/25 Group Datasheet

Rev.	Date		Description
Rev.	Dale	Page	Summary
0.30	Sep 01, 2005	7	Figure 1.4 Pin Assignment • Pin name revised; $VSS \rightarrow VSS/AVSS$, $VCC \rightarrow VCC/AVCC$, $P1_5/RXD0/(TRAIO)/(\overline{INT1}) \rightarrow P1_5/RXD0/(TRAIO)/(\overline{INT1})^{(2)}$, $P6_6/\overline{INT2}/(TXD1) \rightarrow P6_6/\overline{INT2}/TXD1$, $P6_7/\overline{INT3}/(RXD1) \rightarrow P6_7/\overline{INT3}/RXD1$, $P6_5 \rightarrow P6_5/CLK1$ • NOTE2 added
		8	 Table 1.5 Pin Description Analog Power Supply Input: line added INT Interrupt Input: "INT0 Timer RD input pins. INT1 Timer RA input pins." added Serial Interface: "CLK1" added "I²C Bus Interface (IIC)" → "I²C Bus Interface" "SSU" → "Clock Synchronous Serial I/O with Chip Select"
		9	Table 1.6 Pin Name Information by Pin Number revised • Pin Number 10: "VSS" \rightarrow "VSS/AVSS" • Pin Number 12: "VCC" \rightarrow "VCC/AVCC" • Pin Number 27: "INT0" added • Pin Number 28: "(TXD1)" \rightarrow "TXD1" • Pin Number 29: "(RXD1)" \rightarrow "RXD1" • Pin Number 35: "CLK1" added
		15	Tabel 4.1 SFR Information(1) revised: • 0012h: X0h → 00h • 0013h: XXXXX00b → 00h • 0016h: X0h → 00h • 0036h: Voltage Monitor 1 Control Register ⁽²⁾ → Voltage Monitor 1 Control Register ⁽⁵⁾ • 0038h: 00001000b ⁽³⁾ , 01000001b ⁽⁴⁾ → 0000X000b ⁽³⁾ , 0100X001b ⁽⁴⁾ • NOTES2, 5: "the voltage monitor 1 reset" added • NOTE3: "voltage monitor 1 reset" → "voltage monitor 0 reset"
		16	Tabel 4.2 SFR Information(2) revised: • 0048h: RD0IC \rightarrow TRD0IC • 0049h: RD1IC \rightarrow TRD1IC • 004Ah: REIC \rightarrow TREIC • 004Fh: SSU/IIC Interrupt Control Register, IIC2AIC \rightarrow SSU/IIC Interrupt Control Register ⁽²⁾ , SSUAIC/IIC2AIC • 0056h: RAIC \rightarrow TRAIC • 0058h: RBIC \rightarrow TRBIC • NOTE2 added
		17	Tabel 4.3 SFR Information(3) revised: • 00BCh: 00h \rightarrow 00h/0000X000b
		18	 Tabel 4.4 SFR Information(4) revised: 00D6h: 00000XXXb → 00h 00F5h: UART1 Function Select Register, U1SR, XXh added

REVISION HISTORY

R8C/24 Group, R8C/25 Group Datasheet

Davi	Dete		Description
Rev.	Date	Page	Summary
0.40	Jan 24, 2006	46	Package Dimensions; "TBD" \rightarrow "PLQP0052JA-A (52P6A-A)" added
1.00	May 31, 2006	all pages	"Under development" deleted
		1	1. Overview; "data flash ROM" \rightarrow "data flash" revised
		3	Table 1.2 Functions and Specifications for R8C/25 Group revised
		4	Figure 1.1 Block Diagram; "System clock generator" \rightarrow "System clock generation circuit" revised
		5 to 6	Table 1.3 Product Information for R8C/24 Group and Table 1.4 Product Information for R8C/25 Group; A part of (D) mark is deleted.
		9	Table 1.6 Pin Name Information by Pin Number NOTE1 added
		15	Table 4.1 SFR Information(1); 001Ch: "00h" → "00h, 1000000b" revised 0029h: High-Speed On-Chip Oscillator Control Register 4 FRA4 When shipping added 002Bh: High-Speed On-Chip Oscillator Control Register 6 FRA6 When shipping added NOTE6 added
		19	Table 4.5 SFR Information(5); 0118h: Timer RE Second Data Register / Counter Data Register, 0119h: Timer RE Minute Data Register / Compare Data Register register name revised
		20	Table 4.6 SFR Information(6); 0143h: "11000000b" → "11100000b" revised
		22	Table 5.2 Recommended Operating Conditions revised
		24	Table 5.4 Flash Memory (Program ROM) Electrical Characteristics revised
		25	Table 5.5 Flash Memory (Data flash Block A, Block B) Electrical Characteristics revised
		26	Figure 5.2 Time delay until Suspend title revised
		27	Table 5.9 Voltage Monitor 0 Reset Electrical Characteristics → Table 5.9 Power-on Reset Circuit, Voltage Monitor 0 Reset Electrical Characteristics revised Table 5.10 Power-on Reset Circuit Electrical Characteristics (When Not Using Voltage Monitor 0 Reset) deleted Figure 5.3 Power-on Reset Circuit Electrical Characteristics revised
		28	Table 5.10 High-speed On-Chip Oscillator Circuit Electrical Characteristics revised Table 5.11 Low-speed On-Chip Oscillator Circuit Electrical Characteristics revised Characteristics revised
		35	Table 5.16 Electrical Characteristics (2) [Vcc = 5 V] revised
		39	Table 5.22 Electrical Characteristics (4) [Vcc = 3 V] revised
		43	Table 5.28 Electrical Characteristics (6) [Vcc = 2.2 V] revised
		46	Package Dimensions; "The latest package Renesas Technology website." added

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